



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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SANYO Semiconductors

DATA SHEET

SBT80-04J

 — Schottky Barrier Diode (Twin Type · Cathode Common)

40V, 8A Rectifier

Applications

- High frequency rectification (switching regulators, converters, choppers).

Features

- Guaranteed up to $T_j=150^{\circ}\text{C}$.
- Low forward voltage ($V_F \text{ max}=0.55\text{V}$).
- Short reverse recovery time.
- Low switching noise.
- High reliability due to highly reliable planar structure.
- Attachment workability is good by Mica-less package.

Specifications

Absolute Maximum Ratings at $T_a=25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V_{RRM}		40	V
Nonrepetitive Peak Reverse Surge Voltage	V_{RSM}		44	V
Average Output Current	I_O	50Hz resistive load, Sine wave $T_c=117^{\circ}\text{C}$	8	A
Surge Forward Current	I_{FSM}	50Hz sine wave, 1 cycle	80	A
Junction Temperature	T_j		-55 to +150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^{\circ}\text{C}$

Electrical Characteristics at $T_a=25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	V_R	$I_R=1\text{mA}$, $T_j=25^{\circ}\text{C}^*$	40			V
Forward Voltage	V_F	$I_F=3.0\text{A}$, $T_j=25^{\circ}\text{C}^*$			0.55	V
Reverse Current	I_R	$V_R=20\text{V}$, $T_j=25^{\circ}\text{C}^*$			0.1	mA

Note) * : Value per element

Continued on next page.

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SANYO Semiconductor Co., Ltd.

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SBT80-04J

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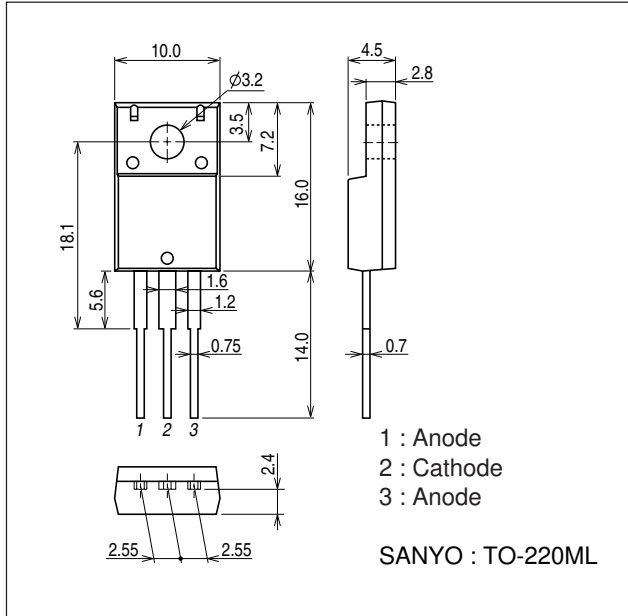
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			min	typ	max	
Interterminal Capacitance	C	$V_R=10V, T_j=25^\circ C^*$		160		pF
Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC			5.0	$^\circ C / W$

Note) * : Value per element

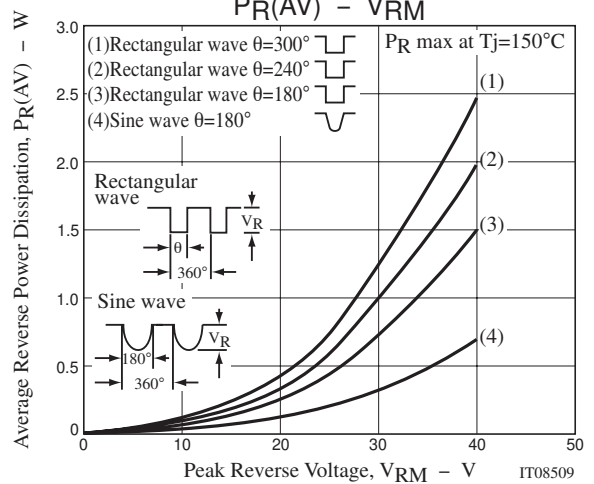
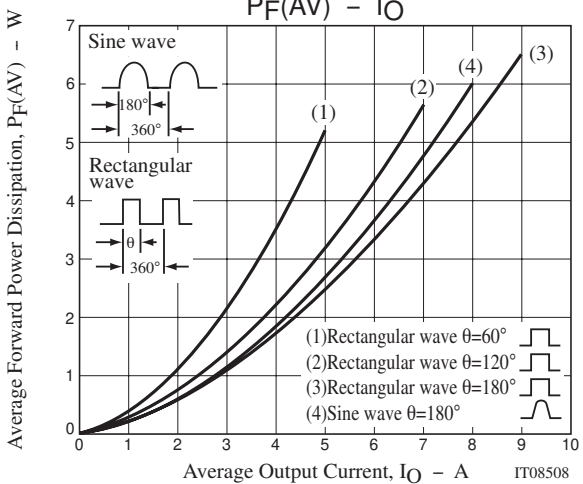
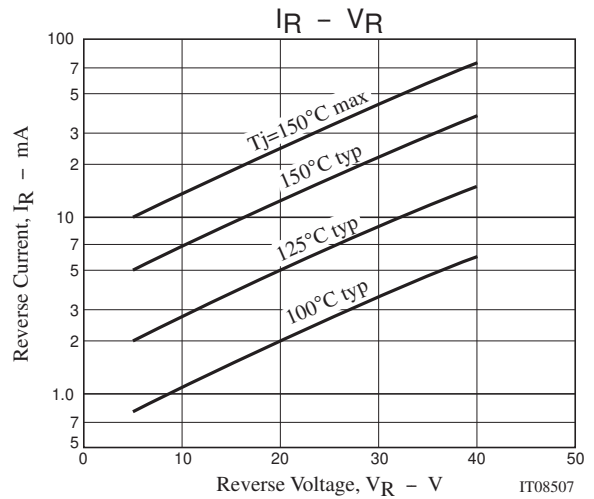
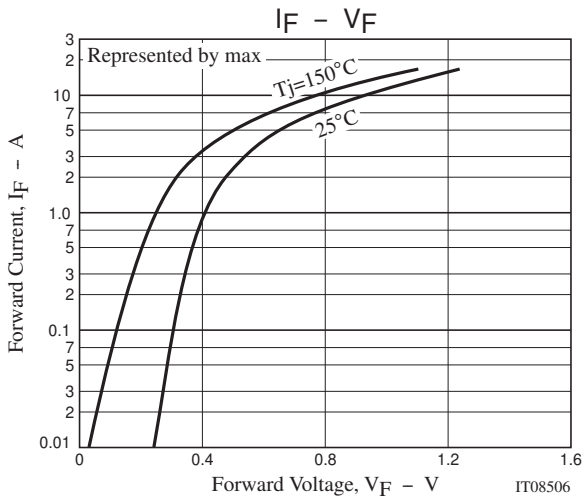
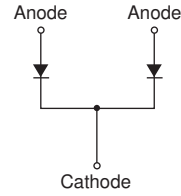
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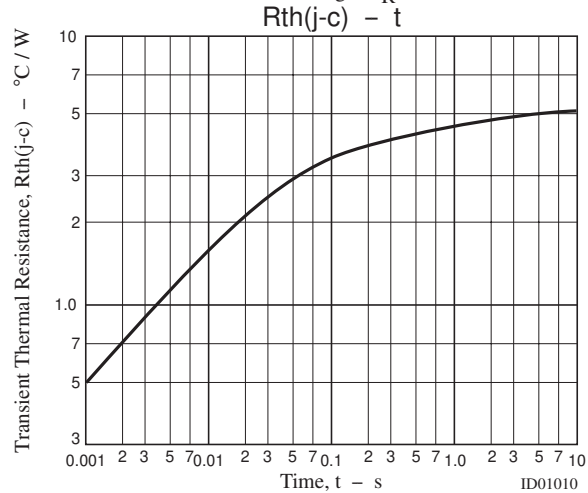
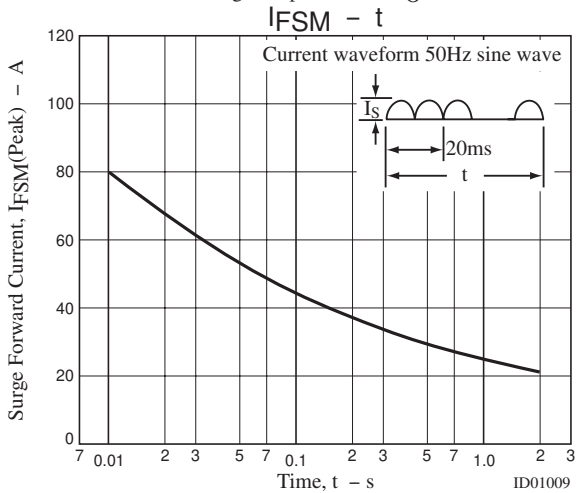
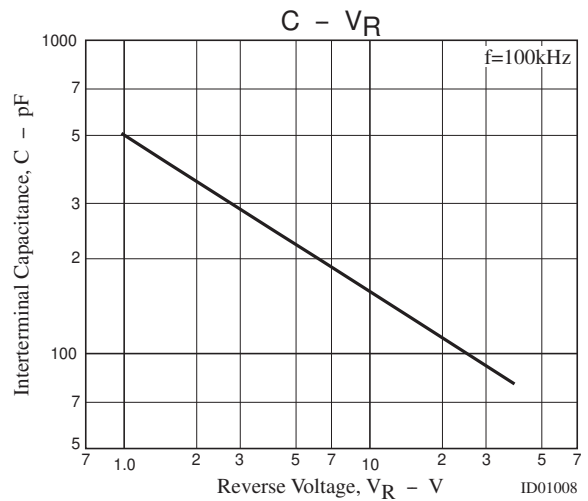
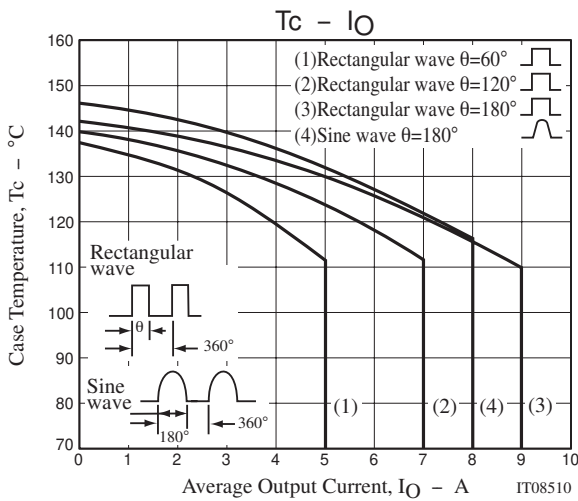
unit : mm (typ)

7508-001



Electrical Connection





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